

# 1N4001G - 1N4007G

1.0 AMP. Glass Passivated Rectifiers

**DO-41**

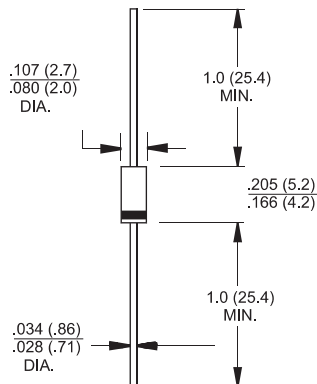


## Features

- ✧ Glass passivated chip junction.
- ✧ High efficiency, Low VF
- ✧ High current capability
- ✧ High reliability
- ✧ High surge current capability
- ✧ Low power loss

## Mechanical Data

- ✧ Cases: Molded plastic
- ✧ Epoxy: UL 94V-0 rate flame retardant
- ✧ Lead: Pure tin plated, lead free., solderable per MIL-STD-202, Method 208 guaranteed
- ✧ Polarity: Color band denotes cathode
- ✧ High temperature soldering guaranteed:  
260 °C /10 seconds/.375", (9.5mm) lead lengths at 5 lbs., (2.3kg) tension
- ✧ Weight: 0.34 gram



Dimensions in inches and (millimeters)

## Maximum Ratings and Electrical Characteristics

Rating at 25 °C ambient temperature unless otherwise specified.

Single phase, half wave, 60 Hz, resistive or inductive load.

For capacitive load, derate current by 20%

Type Number	Symbol	1N	1N	1N	1N	1N	1N	1N	Units
		4001G	4002G	4003G	4004G	4005G	4006G	4007G	
Maximum Recurrent Peak Reverse Voltage	$V_{RRM}$	50	100	200	400	600	800	1000	V
Maximum RMS Voltage	$V_{RMS}$	35	70	140	280	420	560	700	V
Maximum DC Blocking Voltage	$V_{DC}$	50	100	200	400	600	800	1000	V
Maximum Average Forward Rectified Current .375" (9.5mm) Lead Length @ $T_A = 75^\circ C$	$I_{(AV)}$	1.0							A
Peak Forward Surge Current, 8.3 ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method )	$I_{FSM}$	30							A
Maximum Instantaneous Forward Voltage @1.0A	$V_F$	1.0							V
Maximum DC Reverse Current @ $T_A=25^\circ C$ at Rated DC Blocking Voltage @ $T_A=125^\circ C$	$I_R$	5.0 100							$\mu A$ $\mu A$
Typical Junction Capacitance ( Note 1 )	$C_j$	10							pF
Typical Thermal Resistance (Note 2)	$R_{\theta JA}$	80							$^\circ C/W$
Operating and Storage Temperature Range	$T_J, T_{STG}$	- 65 to + 150							$^\circ C$

Notes: 1. Measured at 1 MHz and Applied Reverse Voltage of 4.0 Volts D.C.

2. Mount on Cu-Pad Size 5mm x 5mm on P.C.B.

## RATINGS AND CHARACTERISTIC CURVES (1N4001G THRU 1N4007G)

